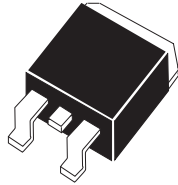


CQDD-16M
CQDD-16N

16 AMP TRIAC
600 THRU 800 VOLTS



D²PAK CASE

CentralTM

Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CQDD-16M series type is an Epoxy Molded Silicon Triac designed for full wave AC control applications featuring gate triggering in all four (4) quadrants.

MARKING CODE: FULL PART NUMBER

MAXIMUM RATINGS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

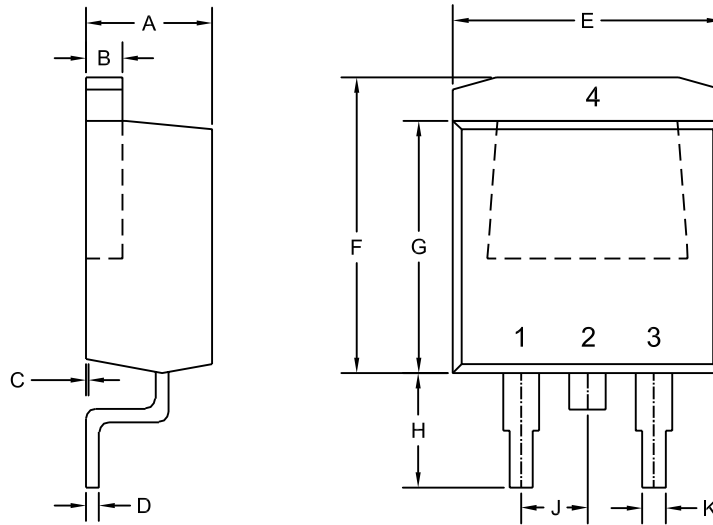
| | SYMBOL | CQDD -16M | CQDD -16N | UNITS |
|---|-------------------|--------------|--------------|--------------------|
| Peak Repetitive Off-State Voltage | V_{DRM} | 600 | 800 | V |
| RMS On-State Current ($T_C=90^\circ\text{C}$) | $I_T(\text{RMS})$ | | 16 | A |
| Peak One Cycle Surge ($t=8.3\text{ms}$) | I_{TSM} | | 110 | A |
| I^2t Value for Fusing ($t=8.3\text{ms}$) | I^2t | | 50 | A ² s |
| Peak Gate Power ($t_p=10\mu\text{s}$) | P_{GM} | | 40 | W |
| Average Gate Power Dissipation | $P_G (AV)$ | | 1.0 | W |
| Peak Gate Current ($t_p=10\mu\text{s}$) | I_{GM} | | 6.0 | A |
| Peak Gate Voltage ($t_p=10\mu\text{s}$) | V_{GM} | | 16 | V |
| Critical Rate of Rise of On-State Current | | | | |
| Repetitive ($f=60\text{Hz}$) | di/dt | | 10 | A/ μs |
| Storage Temperature | T_{stg} | -40 to +150 | | $^\circ\text{C}$ |
| Junction Temperature | T_J | -40 to +125 | | $^\circ\text{C}$ |
| Thermal Resistance | θ_{JA} | | 60 | $^\circ\text{C/W}$ |
| Thermal Resistance | θ_{JC} | | 2.3 | $^\circ\text{C/W}$ |

ELECTRICAL CHARACTERISTICS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

| SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------|---|-----|------|------|------------------|
| I_{DRM} | Rated V_{DRM} | | | 10 | μA |
| I_{DRM} | Rated V_{DRM} , $T_C=125^\circ\text{C}$ | | | 2.0 | mA |
| I_{GT} | $V_D=12\text{V}$, $R_L=10\Omega$, QUAD I, II, III | | 10.9 | 25 | mA |
| I_{GT} | $V_D=12\text{V}$, $R_L=10\Omega$, QUAD IV | | 55.2 | 75 | mA |
| I_H | $I_T=100\text{mA}$ | | 9.8 | 25 | mA |
| V_{GT} | $V_D=12\text{V}$, $R_L=10\Omega$, QUAD I, II, III | | 0.97 | 1.50 | V |
| V_{GT} | $V_D=12\text{V}$, $R_L=10\Omega$, QUAD IV | | 1.51 | 2.50 | V |
| V_{TM} | $I_{TM}=22.5\text{A}$, $t_p=380\mu\text{s}$ | | 1.35 | 1.60 | V |
| dv/dt | $V_D=2/3 V_{DRM}$, $R_{GK}=\infty$, $T_C=125^\circ\text{C}$ | 10 | | | V/ μs |

R1 (24-September 2004)

D²PAK CASE - MECHANICAL OUTLINE



R2

LEAD CODE:

- 1) MT1
- 2) MT2
- 3) GATE
- 4) MT2

MARKING CODE:

FULL PART NUMBER

| SYMBOL | DIMENSIONS | | | |
|--------|------------|-------|-------------|-------|
| | INCHES | | MILLIMETERS | |
| | MIN | MAX | MIN | MAX |
| A | 0.163 | 0.189 | 4.14 | 4.80 |
| B | 0.045 | 0.055 | 1.14 | 1.40 |
| C | 0.000 | 0.010 | 0.00 | 0.25 |
| D | 0.012 | 0.028 | 0.30 | 0.70 |
| E | 0.386 | 0.409 | 9.80 | 10.40 |
| F | 0.378 | 0.417 | 9.60 | 10.60 |
| G | 0.335 | 0.358 | 8.50 | 9.10 |
| H | 0.197 | 0.236 | 5.00 | 6.00 |
| J | 0.093 | 0.108 | 2.35 | 2.75 |
| K | 0.030 | 0.035 | 0.75 | 0.90 |

D2PAK (REV: R2)